MPS ®

The Future of Analog IC Technology®

DESCRIPTION

The MP3385A is a step-up controller with four regulated current channels designed to drive WLED arrays for mid- and large-sized LCD panel backlighting applications.

The MP3385A uses peak-current mode and PWM control architecture for system loop regulation. The MP3385A drives an external MOSFET to boost up the output voltage from a 4.5V-to-33V input supply.

The MP3385A employs an I^{2}C digital interface that can flexibly set operation and protection modes, including dimming mode, dimming current and dimming ratio, OCP, OVP, LED short protection threshold, and switching frequency. For easy application use and board debugging, the MP3385A detects and disables the unused LED strings automatically during start-up to avoid charging the output to the OVP threshold.

The MP3385A achieves 1.8% current matching between each string. The low regulation voltage on the LED current sources improves efficiency and reduces power loss to achieve a higher current output.

The MP3385A supports analog, PWM, and combined analog and PWM dimming modes to meet different application requirements. Full protection features include over-current protection (OCP), over-temperature protection (OTP), under-voltage protection (UVP), over-voltage protection (OVP), LED short/open protection, and inductor/diode short protection.

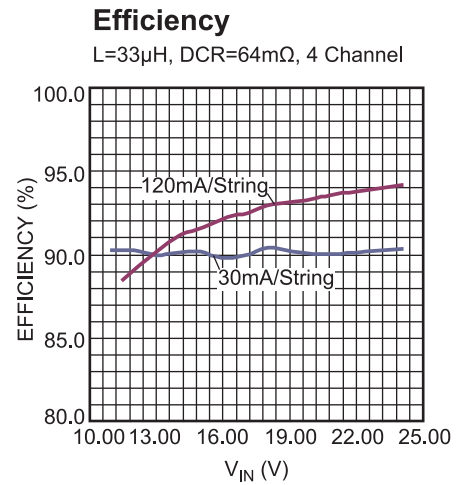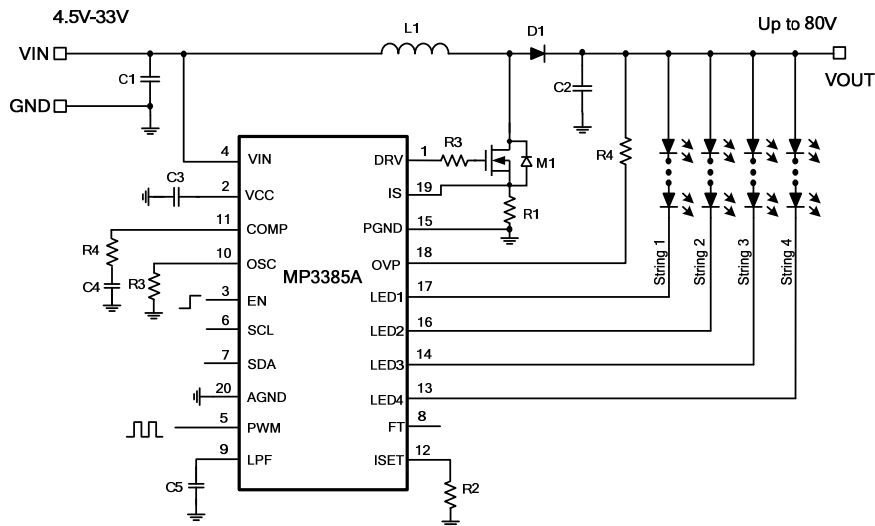The MP3385A is available in a QFN-20 (4mmx4mm) package.

FEATURES

- 4-String, Max 300mA/String WLED Driver
- 4.5V to 33V Input Voltage Range
- 80V ABS Rating for Each String
- 1.8% Current Matching Accuracy for Each String
- Unused Channel Auto-Detection Function during Start-Up
- 100kHz-900kHz Programmable Switching Frequency
- Multiple Dimming Modes Selected by I^{2}C Interface
  o Direct PWM Dimming Mode
  o Internal Fixed 23kHz PWM Dimming Mode by I^{2}C
  o Analog Dimming Mode by Input Pulse
  o Internal Analog Dimming Mode by I^{2}C
  o Mixed Dimming Mode by Input Pulse
  o Internal Mixed Dimming Mode by I^{2}C
- 2%-100% Programmable Full Scale Current with 8-Bit Resolution
- 0%-100% LED Dimming Range with 10-Bit Resolution for Internal Dimming Mode
- Cascading Capability with a Single Power Source
- 18V to 80V Over-Voltage Protection (OVP), 2V/Step
- 0.15V to 0.5V Latch-Off/Recoverable Over-Current Protection (OCP) Threshold, 50mV/Step
- Recoverable Thermal Shutdown Protection

APPLICATIONS

- Desktop LCD Flat Panel Displays
- All-in-One PCs
- 2D/3D LCD TVs

TYPICAL APPLICATION

4.5V-33V

VIN

GND

C1

L1

D1

C2

Up to 80V

VOUT

R3

M1

R4

String 1

String 2

String 3

String 4

Pin	MP3385A		Pin
4	VIN	DRV	1
2	VCC	IS	19
11	COMP	PGND	15
10	OSC	OVP	18
3	EN	LED1	17
6	SCL	LED2	16
7	SDA	LED3	14
20	AGND	LED4	13
5	PWM	FT	8
9	LPF	ISET	12

C3

R4

R3

C4

C5

R1

R2

Efficiency

L=33μH, DCR=64mΩ, 4 Channel

120mA/String

30mA/String

EFFICIENCY (%)

100.0
95.0
90.0
85.0
80.0

10.00 13.00 16.00 19.00 22.00 25.00

V_IN (V)

ORDERING INFORMATION

Part Number*	Package	Top Marking
MP3385AGR	QFN-20 (4mmx4mm)	*See Below*

* For Tape & Reel, add suffix –Z (e.g. MP3385AGR–Z)

TOP MARKING
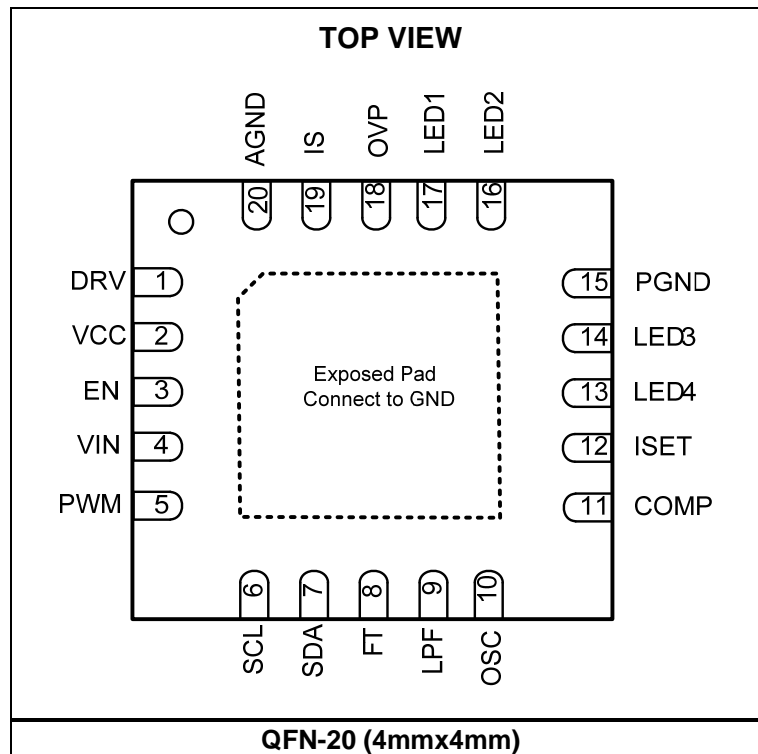
MPSYWW

M3385A

LLLLLL

MPS: MPS prefix
Y: Year code
WW: Week code
M3385A: Part number
LLLLLL: Lot number

PACKAGE REFERENCE

TOP VIEW

QFN-20 (4mmx4mm)

ABSOLUTE MAXIMUM RATINGS [1]

V_{IN} ....-0.3V to +40V

V_{OVP}, V_{LED1} to V_{LED4} ....-0.3V to +80V

All other pins ... -0.3V (-0.5V for <10ns) to +6.5V

Continuous power dissipation (T_A = 25°C) [2]

QFN-20 (4mmx4mm)................................ 2.97W

Junction temperature ....150°C

Lead temperature ....260°C

Recommended Operating Conditions [3]

Supply voltage (V_{IN}) ....4.5V to 33V

Operating junction temp........... -40°C to +125°C

Thermal Resistance [4] θ_{JA} θ_{JC}

QFN-20 (4mmx4mm)............. 42........ 9.... °C/W

NOTES:
1) Exceeding these ratings may damage the device.
2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
3) The device is not guaranteed to function outside of its operating conditions.
4) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS
V_{IN} = 12V, V_{EN} = 5V, T_A = 25°C, unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ	Max	Unit
Operating input voltage	V_{IN}		4.5		33	V
Supply current (quiescent)	I_Q	V_{IN} = 12V, no switching		3		mA
Supply current (shutdown)	I_{ST}	V_{EN} = 0V, V_{IN} = 12V			1	µA
LDO output voltage	V_{CC}	7V < V_{IN} < 28V, 0 < I_{VCC} < 10mA	5.4	6	6.3	V
VCC UVLO threshold	V_{IN_UVLO}	Rising edge	3.7	4	4.3	V
VCC UVLO hysteresis				340		mV
EN high voltage	V_{EN_HIGH}	V_{EN} rising	1.5			V
EN low voltage	V_{EN_LOW}	V_{EN} falling			0.6	V
Step-Up Converter						
Gate driver sourcing impedance		V_{CC} = 6V, V_{GATE} = 6V		4		Ω
Gate driver sinking impedance		V_{CC} = 6V, I_{GATE} = 10mA		2		Ω
Switching frequency	f_{SW}	FS3:0 bits = 0010b, R_{OSC} = 100kΩ	156	195	234	kHz
		FS3:0 bits = 1001b, R_{OSC} = 100kΩ	672	820	967	kHz
OSC voltage	V_{OSC}	R_{OSC} = 100kΩ, f_{SW} = 900kHz	1.75	1.79	1.83	V
Maximum duty cycle	D_{MAX}		90			%
Cycle-by-cycle IS pin current limit		OCP2:0 bits = 000b	130	150	170	mV
		OCP2:0 bits = 111b	465	500	535	mV
COMP source current limit	$I_{COMP\ SOLI}$	1V < COMP < 2.9V		75		µA
COMP sink current limit	$I_{COMP\ SILI}$	1V < COMP < 2.9V		15		µA
COMP transconductance	G_{COMP}	ΔI_{COMP} = ±10µA		100		µA/V
Current Dimming						
PWM input low threshold	V_{PWM_LO}	V_{PWM} falling			0.4	V
PWM input high threshold	V_{PWM_HI}	V_{PWM} rising	1.5			V
Dimming transfer point		MODE1:0 bits = 10b		25		%
		MODE1:0 bits = 11b		50		%
Internal dimming frequency			20	23		kHz
Dimming ratio		Dimming resolution		0.098		%
		DIM = 1111111111b		100		%

ELECTRICAL CHARACTERISTICS *(continued)*

V$_{IN}$ = 12V, V$_{EN}$ = 5V, T$_A$ = 25°C, unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ	Max	Unit
Current Regulation						
ISET voltage	V$_{ISET}$		1.93	1.98	2.03	V
LEDX average current	I$_{LED}$	R$_{ISET}$ = 100.8kΩ, ILED = FFh	192	201	210	mA
Full scale current		ILED7:0 bits = 00h		2		%
		ILED7:0 bits = FFh$^{(5)}$		100		%
Current matching [6]		I$_{LED}$ = 200mA			1.8	%
LEDX regulation voltage	V$_{LEDX}$	I$_{LED}$ = 330mA		820		mV
		I$_{LED}$ = 200mA		700		mV
		I$_{LED}$ = 60mA		500		mV
Protection						
OVP threshold	V$_{OVP\_OV}$	OVP4:0 bits = 00000b	16.8	18	18.9	V
		OVP4:0 bits = 11100b	71.5	74	75.5	V
OVP UVLO threshold	V$_{OVP\_UV}$	Step-up converter fails		2.5		V
LEDX UVLO threshold	V$_{LEDX\_UV}$		147	206	265	mV
LEDX over-voltage threshold	V$_{LEDX\_OV}$	LEDS2:0 bits = 000b		4		V
		LEDS2:0 bits = 111b		11		V
Thermal protection threshold	T$_{ST}$			150		°C
Thermal protection hysteresis				25		°C
I^{2}C Interface Specifications						
Input logic low	V$_{IL}$				0.4	V
Input logic high	V$_{IH}$		1.3			V
Output logic low	V$_{OL}$	I$_{LOAD}$ = 3mA			0.4	V
SCL clock frequency	f$_{SCL}$				400	kHz
SCL high time	τ$_{HIGH}$		0.6			µs
SCL low time	τ$_{LOW}$		1.3			µs
Data set-up time	τ$_{SU,DAT}$		100			ns
Data hold time	τ$_{HD,DAT}$		0		0.9	µs
Set-up time for repeated start	τ$_{SU,STA}$		0.6			µs
Hold time for start	τ$_{HD,STA}$		0.6			µs
Bus-free time between a start and stop condition	τ$_{BUF}$		1.3			µs
Set-up time for stop condition	τ$_{SU,STO}$		0.6			µs
Rise time of SCL and SDA	τ$_R$		20 + 0.1 x C$_B$		300	ns
Fall time of SCL and SDA	τ$_F$		20 + 0.1 x C$_B$		300	ns
Pulse width of suppressed spike	τ$_{SP}$		0		50	ns
Capacitance bus for each bus line	C$_B$				400	pF

NOTES:
5) Guaranteed by design.
6) Matching is defined as the difference between the maximum to minimum current divided by 2x the average currents.
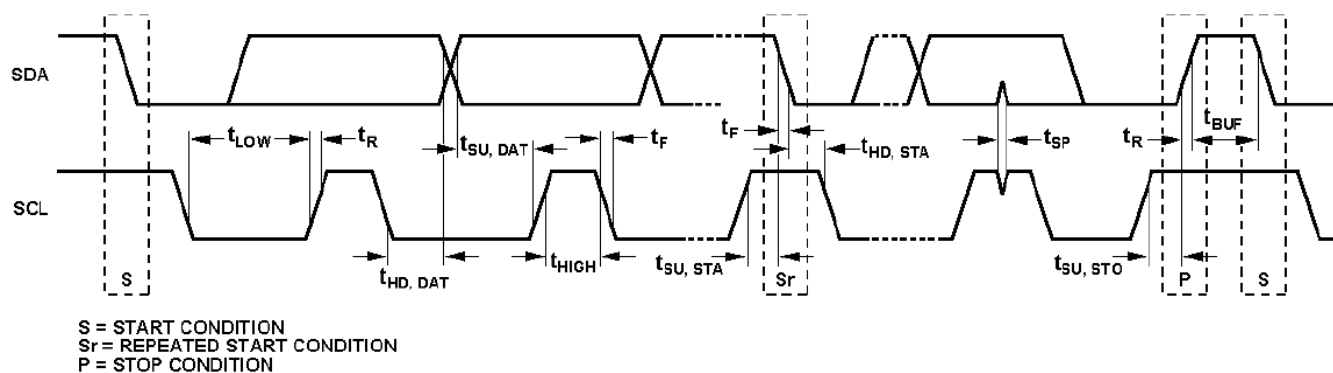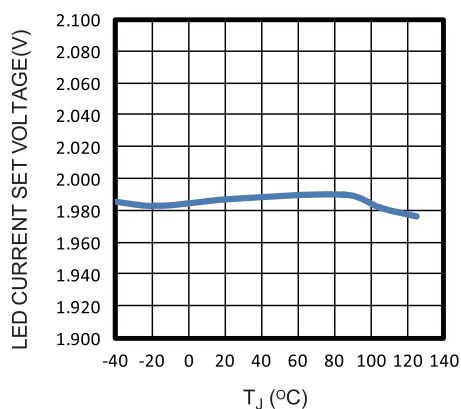
TIMING DIAGRAM

S = START CONDITION
Sr = REPEATED START CONDITION
P = STOP CONDITION

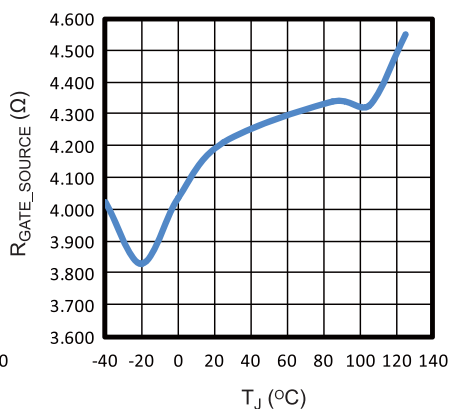**Figure 1: I^{2}C Compatible Interface Timing Diagram**

TYPICAL PERFORMANCE CHARACTERISTICS

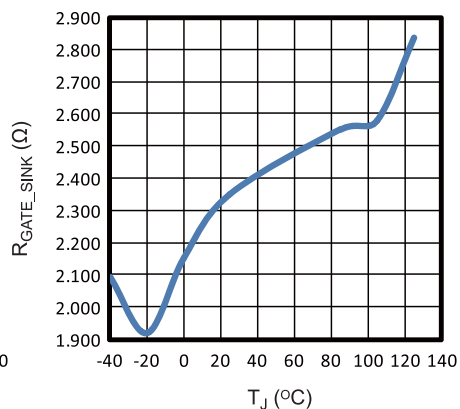V_{IN} = 12V, V_{EN} = 3.3V, unless otherwise noted.
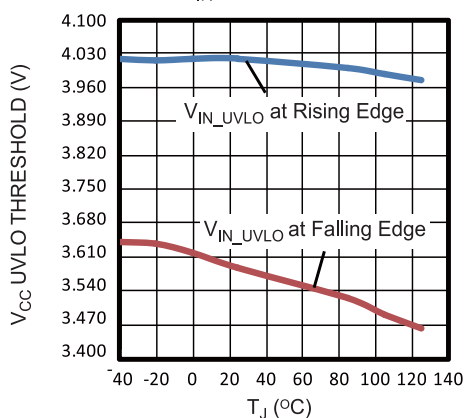
V_{ISET} vs. T_J
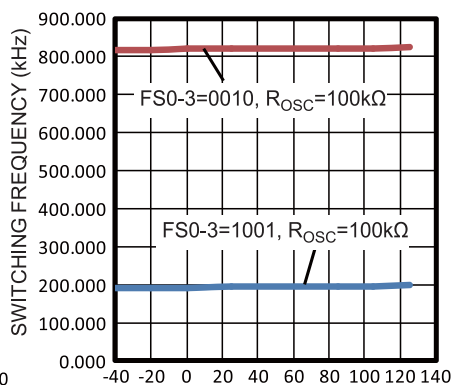
R_{GATE_SOURCE} vs. T_J

R_{GATE_SINK} vs. T_J

V_{IN_UVLO} vs. T_J
Sweep V_{IN}

F_{SW} vs. T_J

TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

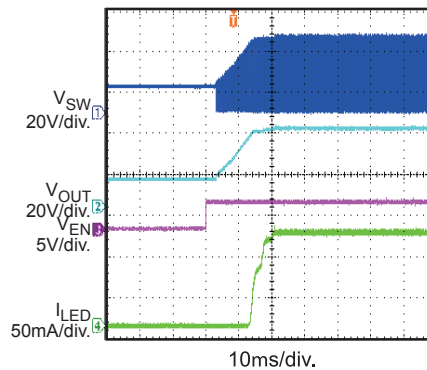V_{IN} = 12V, V_{EN} = 3.3V, L = 33µH, 120mA/string, 4 strings, 14 LEDs, T_A = 25°C, unless otherwise noted.

Steady State

2µs/div.
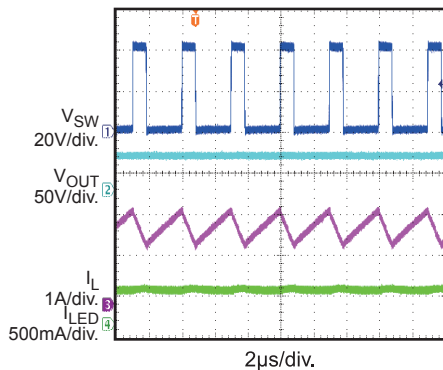
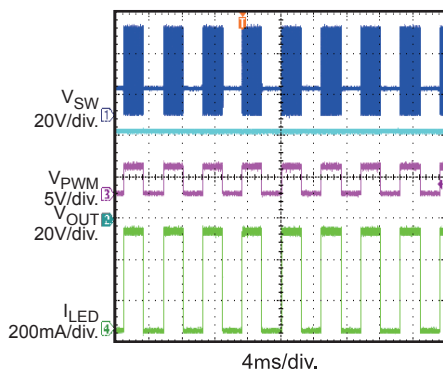**V$_{IN}$ Power On
30mA/String**

10ms/div.
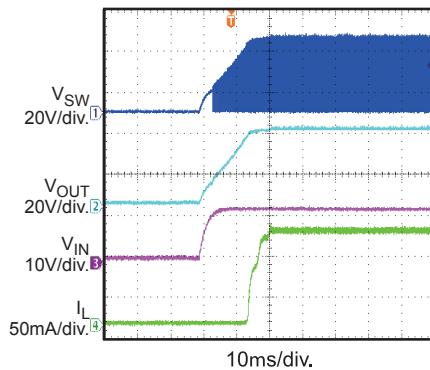
**EN Power On
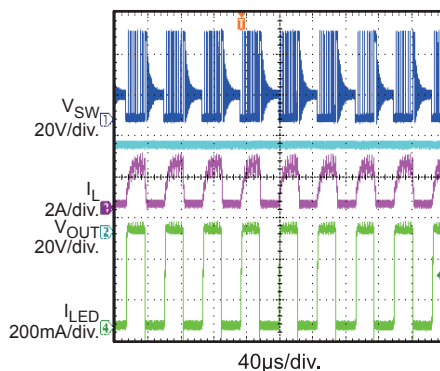30mA/String**

10ms/div.

**PWM Dimming
by PWM Input**
f_{PWM} = 200Hz, D_{PWM} = 50%
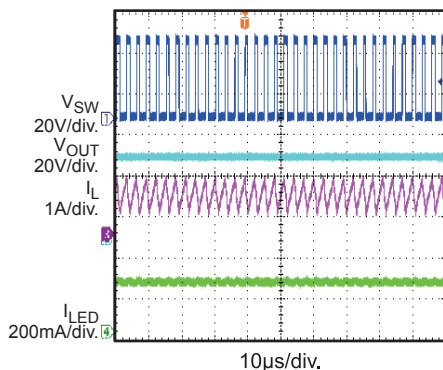

4ms/div.

**PWM Dimming
by I²C Interface**
D_{DIM} = 50%

40µs/div.

**Analog Dimming
by PWM Input**
f_{PWM} = 20kHz, D_{PWM} = 50%

10µs/div.
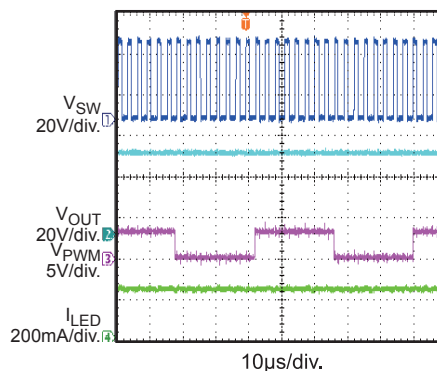
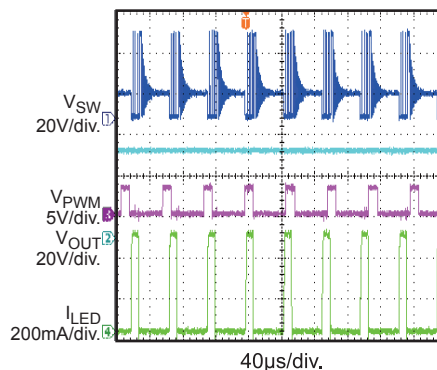**Analog Dimming
by I²C Interface**
D_{DIM} = 50%

10µs/div.

**Mix Dimming
by PWM Input**
f_{PWM} = 20kHz, D_{PWM} = 60%

10µs/div.
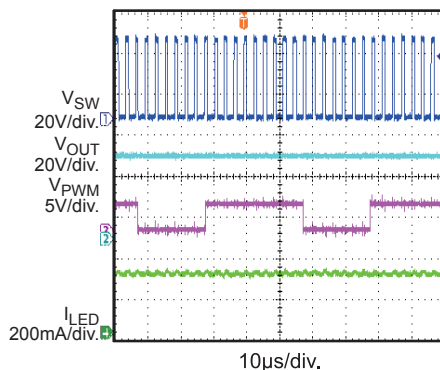
**Mix Dimming
by PWM Input**
f_{PWM} = 20kHz, D_{PWM} = 20%

40µs/div.

TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{EN} = 3.3V, 120mA/string, 4 strings, 14 LEDs, T_A = 25°C, unless otherwise noted.

**Mix Dimming
by I²C Interface**
D_{DIM} = 60%

10µs/div.
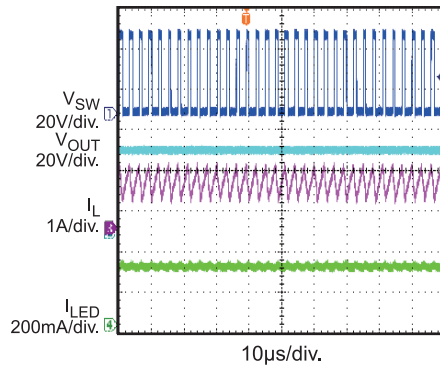
**Mix Dimming
by I²C Interface**
D_{DIM} = 20%

40µs/div.
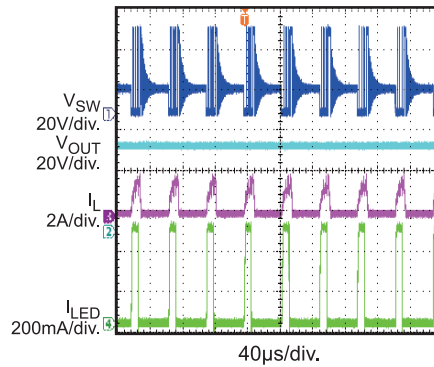
**Unused String Protection
when V_{IN} Power On**

10ms/div.

Open One String

10ms/div.

Short One String

10ms/div.

Short Inductor Protection

20µs/div.

Short Diode Protection
30mA/String

10µs/div.
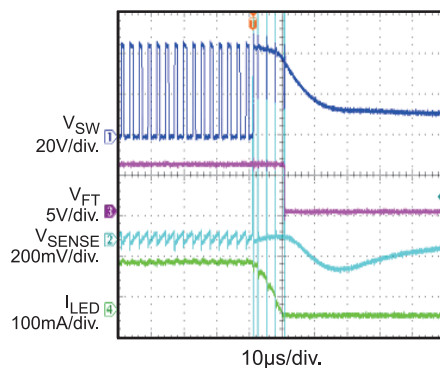
PIN FUNCTIONS

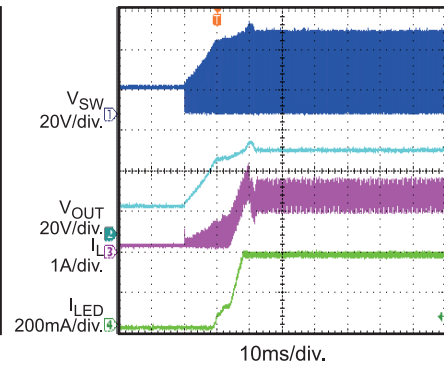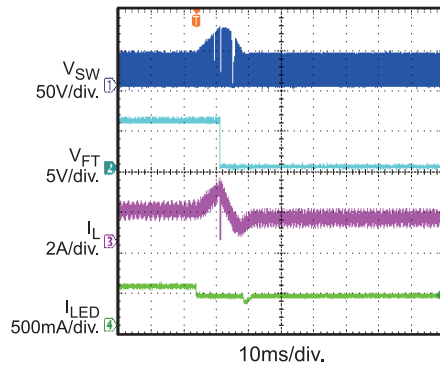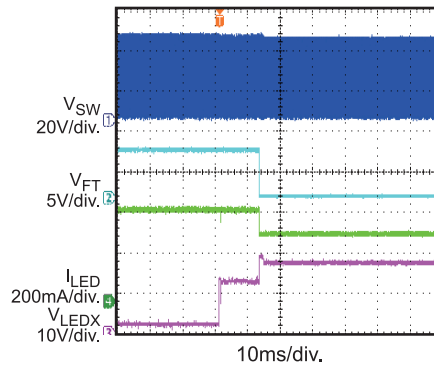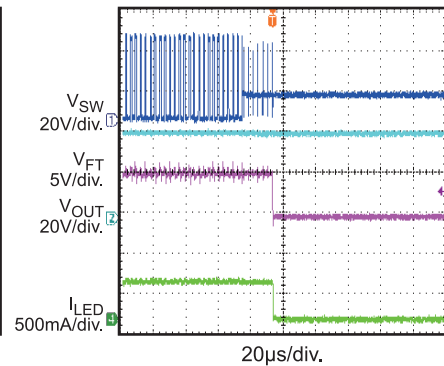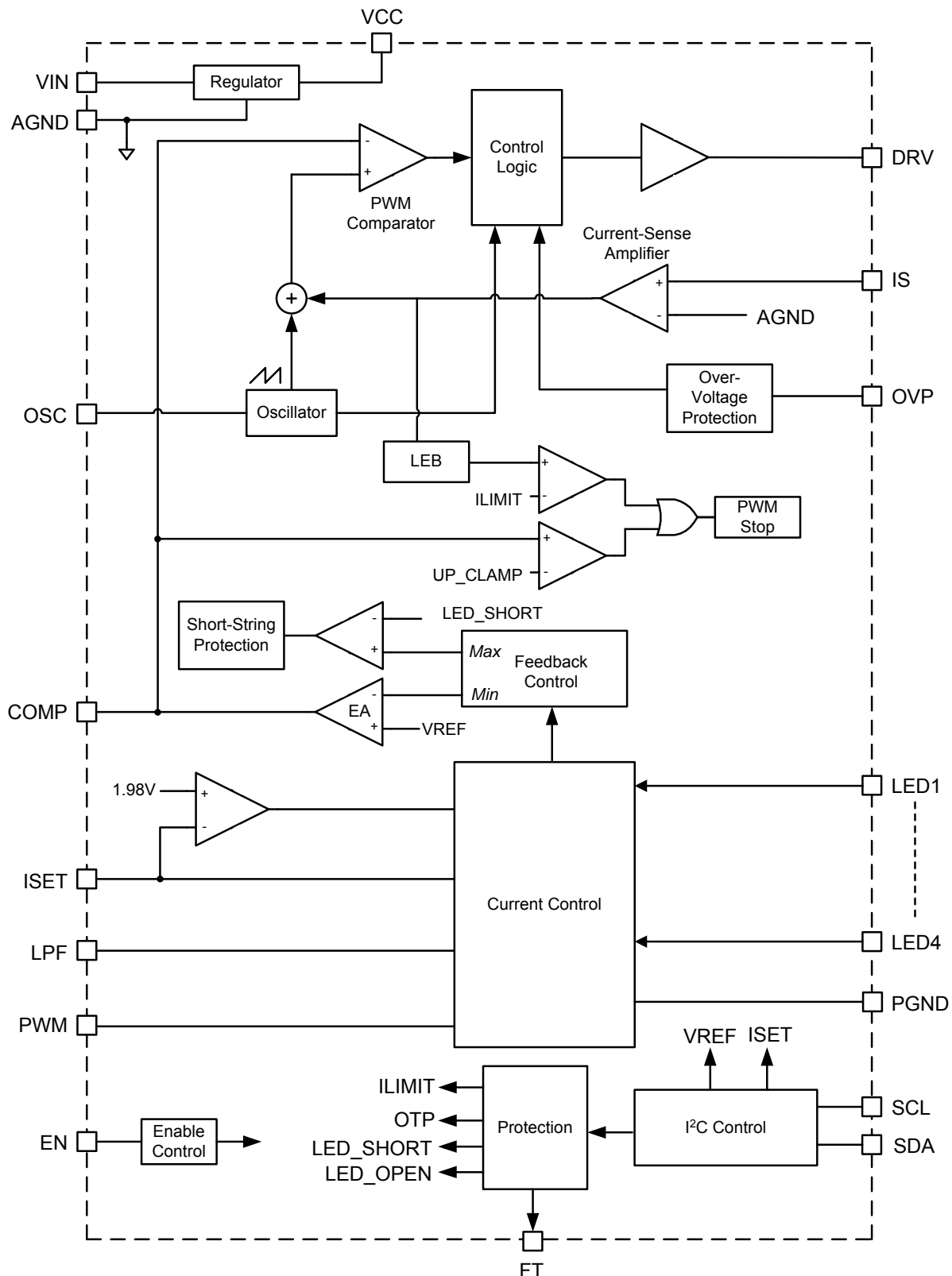| Package Pin #	Name	Description
1	DRV	**Step-up converter power switch gate output.** DRV drives the external power N-channel MOSFET device. Connect a resistor (e.g.: 10Ω) to DRV.
2	VCC	**Internal 6V linear regulator output.** VCC provides a power supply for the external MOSFET switch gate driver and internal control circuitry. Bypass VCC to GND with a ceramic capacitor.
3	EN	**Enable control input.** A voltage greater than 1.5V turns the part on. A voltage less than 0.6V turns the part off. Do not float EN.
4	VIN	**Supply input.** VIN must be bypassed locally.
5	PWM	**PWM input signal for brightness control.** Ensure that the PWM amplitude voltage level is higher than V_{PWM_HI}, and the low-level voltage is lower than V_{PWM_LO}. The input PWM signal frequency determines the LED current dimming ratio when the MP3385A works in direct PWM dimming mode. For external analog and mixed dimming modes, the PWM pulse is filtered to a DC signal by an LPF capacitor, and the LED current is proportional to the input PWM duty. If PWM is floated, weakly pull PWM to GND internally.
6	SCL	**I²C clock input.**
7	SDA	**I²C data input.**
8	FT	**Fault indication output**. FT is an open drain during normal operation. FT is pulled low during a fault condition.
9	LPF	**Low-pass filter output for analog dimming with PWM input.** A capacitor is connected between LPF and GND when the part operates in external PWM input analog dimming or mixed dimming mode. Remove the LPF capacitor when the part operates in direct PWM dimming mode.
10	OSC	**Switching frequency set.** Connect a resistor (R_{OSC}) between OSC and GND to set the step-up converter switching frequency. The clock frequency is proportional to the current sourced from OSC. There is a 100~900kHz switching frequency selected by the I²C interface when connected to a 100kΩ resistor at OSC.
11	COMP	**Step-up converter compensation.** COMP compensates for the regulation control loop. Connect a ceramic capacitor and resistor from COMP to GND.
12	ISET	**LED current set.** Tie a current-setting resistor from ISET to ground to program the current in each LED string.
13	LED4	**LED string 4 current input.** LED4 is the open-drain output of an internal dimming control switch. Connect the LED string 4 cathode to LED4.
14	LED3	**LED string 3 current input.** LED3 is the open-drain output of an internal dimming control switch. Connect the LED string 3 cathode to LED3.
15	PGND	**Power ground.**
16	LED2	**LED string 2 current input.** LED2 is the open-drain output of an internal dimming control switch. Connect the LED string 2 cathode to LED2.
17	LED1	**LED string 1 current input.** LED1 is the open-drain output of an internal dimming control switch. Connect the LED string 1 cathode to LED1.
18	OVP	**Output over-voltage protection.**
19	IS	**Current sense input.** During normal operation, IS senses the voltage across the external inductor current-sensing resistor (R_{SENSE}) for peak-current-mode control. IS also limits the inductor current during every switching cycle. If the MP3385A is used for cascading applications, tie IS of the slave chip to GND. Do not float IS.
20	AGND	**Signal ground.**

BLOCK DIAGRAM

Figure 2: Functional Block Diagram

OPERATION

The MP3385A employs a programmable, constant-frequency, peak-current mode, step-up converter with four regulated current channels to drive an array of four strings of white LEDs. The MP3385A has an I²C interface for easy communication that sets the operation modes flexibly.

Internal 6V Regulator

The MP3385A includes an internal linear regulator (VCC). When VIN is greater than 6.5V, the regulator outputs a 6V power supply to the external MOSFET switch gate driver and the internal control circuitry. The VCC voltage drops to 0V when the chip shuts down. The MP3385A features under-voltage lockout (UVLO), in which the chip is disabled until VCC exceeds the UVLO threshold. The UVLO hysteresis is approximately 340mV.

System Start-Up

When enabled, the MP3385A checks the topology connection first. The chip monitors the over-voltage protection (OVP) pin to determine if the Schottky diode is connected or if the boost output is shorted to GND. An OVP voltage higher than 2.5V allows the chip to switch normally. Otherwise, switching is disabled. The MP3385A checks additional safety limits including LED open/short protection, UVLO, over-temperature protection (OTP), and over-current protection (OCP) after passing the OVP test. If all the protection tests pass, the chip begins boosting the step-up converter with an internal soft start.

Step-Up Converter

At the beginning of each switching cycle, the internal clock turns on the external MOSFET. In normal operation, the minimum turn-on time is around 150ns. A stabilizing ramp is added to the output of the current sense amplifier to prevent sub-harmonic oscillations for duty cycles greater than 50%. This result is fed into the PWM comparator. When the summed voltage reaches the output voltage of the error amplifier (V_{COMP}), the external MOSFET turns off.

The output voltage of the internal error amplifier is an amplified signal of the difference between the reference voltage and the feedback voltage.

The converter chooses the lowest active LEDX voltage automatically to provide a high-enough bus voltage to power all of the LED arrays.

If the feedback voltage drops below the reference, the output of the error amplifier increases. This results in more current flowing through the MOSFET, increasing the power delivered to the output. This forms a closed loop that regulates the output voltage.

Under light-load operation, especially in the case of $V_{OUT} \approx V_{IN}$, the converter runs in pulse-skipping mode where the MOSFET turns on for a minimum on time, and then the converter discharges the power to the output for the remaining period. The external MOSFET remains off until the output voltage needs to be boosted again.

Dimming Control

The MP3385A provides flexible dimming methods according to the dimming mode settings below.

1) *PWM Dimming Mode*

MODE bits = 00b. The LED current duty cycle directly follows the PWM input signal duty cycle when INTERFACE = 0. The IC works in internal PWM dimming mode, and the LED current duty cycle is set by the internal registers 03H and 04H when INTERFACE = 1. The internal dimming frequency is fixed at 23kHz.

2) *Analog Dimming Mode*

MODE bits = 01b. The LED current amplitude follows the duty cycle of the input PWM signal when INTERFACE = 0. The IC works in internal analog dimming mode (the LED current amplitude follows the internal register value of 03H and 04H) if INTERFACE = 1.

3) *Mixed Dimming Mode*

There are two transfer points from analog to PWM dimming (25% or 50%) set by the I²C interface.

If the MODE bits = 10b when the dimming duty cycle is larger than the 25% threshold, the IC works in analog dimming mode. Otherwise, the IC works in PWM dimming mode, and the LED current follows the PWM ratio. If the MODE bits = 11b when the dimming duty cycle is larger than the 50% threshold, the IC works in analog dimming mode. Otherwise, the IC works in PWM dimming mode.

In mixed dimming mode, when INTERFACE = 0, the LED current amplitude is proportional to the ratio of the external PWM signal if the duty cycle of PWM is larger than the transfer point (25% or 50%). The LED current amplitude is fixed to 100% brightness while the LED current duty is equal to the input PWM ratio (if the duty cycle of PWM is lower than the transfer point). When INTERFACE = 1, the LED current amplitude and the duty cycle are set by registers 03H and 04H.

Regardless of the INTERFACE setting (1 or 0), the LED current frequency is fixed at 23kHz in mixed dimming mode when the duty cycle is lower than the transfer point (25% or 50%).

In analog and mixed dimming mode, to avoid noise at the small dimming ratio, the IC turns off the current sources if the current is less than 1.2% times the full scale current.

For external analog and mixed dimming modes, the minimum pulse width of the PWM signal is limited to 2µs to avoid noise interruption.

Operation Switching Frequency

The operation frequency of the converter can be changed by the OSC resistor and the FS0-3 bit in register 01H. The switching frequency covers 100kHz to 900kHz through the I²C register bits when a 100kΩ resistor is connected to OSC. This optimizes the size of the external components and system efficiency.

Open-String Protection

Open-string protection is achieved through the OVP pin and the LED (1 to 4) pins. If one or more strings are open, the respective LEDX pins are pulled to ground. The IC continues charging the output voltage until it reaches the over-voltage protection (OVP) threshold. If the OVP point has been triggered, the chip stops switching and marks the strings that have an LEDX pin voltage lower than 206mV. Once

marked, the remaining LED strings force the output voltage back into tight regulation. The string with the largest voltage drop determines the output regulation.

The MP3385A always attempts to light at least one string. If all strings are open, the MP3385A shuts down the step-up converter. The strings remain in this marked state until the chip resets.

Unused LED String Auto-Detection

For the MP3385A, if an LED string is open or unused before start-up, the IC detects and marks off the open channel automatically to prevent the output from charging to the OVP value. This function prevents a start-up failure, which is caused by LED short string misprotection due to OVP triggering. This is useful for application use and test board debugging. The unused LED string auto-detection function is disabled if the OVP point is changed by the I²C after EN and VIN power on, and I²C is active.

The MP3385A disables the unused LED string by disabling the corresponding register control bit for each 4-channel current source. In some applications, if fewer than four LED strings are needed, the unused LED current sources can be disabled by setting the LED4:0 bit to 0 in register 00H.

Short-String Protection

The MP3385A monitors the LEDX pin voltages to determine if a short-string fault has occurred. If one or more strings are shorted, the respective LEDX pins tolerate high-voltage stress. If an LEDX pin voltage is higher than the protection threshold, which can be programmable by the LEDS2:0 bits in 01H, this condition triggers the detection of a short-string fault. When a short-string fault remains for longer than 10ms, the fault string is marked off and disabled. Once a string is marked off, it disconnects from the output voltage loop until VIN or EN restarts.

Cycle-by-Cycle Current Limit

To prevent the external components from exceeding the current stress rating, the IC uses a cycle-by-cycle current limit protection. The limit value is programmable from 150mV to

500mV by the OCP2:0 bits in register 05H. When the current exceeds the current limit value, the IC latches off until the power is reset or EN is toggled when operating in latch-off mode if the OCPM bit = 0. The device restarts when the current drops below the current limit again if the OCPM bit = 1.

Short Inductor/Diode Protection

When the external inductor or diode is shorted, the IC provides protection by detecting the current flowing through the power MOSFET. When the current sense voltage across the sense resistor (connected between IS and GND) hits the current protection threshold and lasts for four switching cycles, the IC stops switching and latches.

Thermal Shutdown Protection

To prevent the IC from operating at exceedingly high temperatures, thermal shutdown is implemented to detect the silicon die temperature. When the die temperature exceeds the upper threshold (T_{ST}), the IC shuts down. The IC resumes normal operation when the die temperature drops below the lower threshold. Typically, the hysteresis value is 25°C.

Fault Flag Output and Fault Register Indicator

FT remains in an open-drain condition when the LED driver is operating in a normal condition. It is connected to VCC by an external 100kΩ resistor and pulled to logic high when there is no fault. FT goes to logic low if a fault occurs. Set the corresponding fault bit in register 03H to 1.

I²C Interface Register Description

I²C Chip Address

After the start condition, the I²C-compatible master sends a 7-bit address followed by an eighth read (Read: 1) or write (Write: 0) bit. The bit indicates the register address to or from which the data is written or read (see Figure 3).

0	1	1	0	0	0	1	R/W

Figure 3: The I²C Compatible Device Address

Register Mapping

Add	D7	D6	D5	D4	D3	D2	D1	D0
00H	LED4	LED3	LED2	LED1	NA	INTERFACE	MODE1	MODE0
01H	OCPM	LEDS2	LEDS1	LEDS0	FS3	FS2	FS1	FS0
02H	ILED7	ILED6	ILED5	ILED4	ILED3	ILED2	ILED1	ILED0
03H	DIODEO_F	OVP_F	OCP_F	LEDS_F	LEDO_F	OTP_F	DIM1	DIM0
04H	DIM9	DIM8	DIM7	DIM6	DIM5	DIM4	DIM3	DIM2
05H	OVP4	OVP3	OVP2	OVP1	OVP0	OCP2	OCP1	OCP0
06H	ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0

Table 1: Dimming Mode Register

Addr: 0x00				
Bit	**Bit Name**	**Access**	**Default**	**Description**

7:4	LED4:0	RW	1111b	LED current source enable bits. LED1/2/3/4 controls the internal LED current sources, respectively.
				
				LED1: LED current source 1
				
				  1 = enabled
				
				  0 = disabled
				
				LED2: LED current source 2
				
				  1 = enabled
				
				  0 = disabled
				
				LED3: LED current source 3
				
				  1 = enabled
				
				  0 = disabled
				
				LED4: LED current source 4
				
				  1= enabled
				
				  0 = disabled

3	NA	RW	NA	N/A
2	INTERFACE	RW	0b	Dimming input interface set bit. 0 = dimming control by PWM input signal 1 = dimming control by I²C interface
1:0	MODE1:0	RW	00b	Dimming mode setting bits. 00 = PWM mode. The LED current duty cycle directly follows the PWM input signal duty cycle when INTERFACE = 0. The IC works in internal PWM dimming mode, and the LED current duty cycle is set by the internal registers 03H and 04H when INTERFACE = 1. The internal dimming frequency is fixed at 23kHz. 01 = Analog dimming mode. The LED current amplitude follows the duty cycle of the input PWM signal when INTERFACE = 0 and follows the internal register value of 03H and 04H if INTERFACE = 1. 10 = Mixed dimming mode. When the dimming duty cycle is larger than the 25% threshold, the IC works in analog dimming mode. Otherwise, the IC works in PWM dimming mode. 11 = Mixed dimming mode. When the dimming duty cycle is larger than the 50% threshold, the IC works in analog dimming mode. Otherwise, the IC works in PWM dimming mode.

Table 2: Operation Frequency Register

				Addr: 0x01			

Bit	Bit Name	Access	Default	Description
7	OCPM	RW	0b	Mode selection bit for cycle-by-cycle current limit. 0 = latch-off mode current limit 1 = recoverable mode current limit
4:6	LEDS2:0	RW	100b	LED short protection threshold. 1V/step. Default value is 8V. 000 = 4V 001 = 5V 111 = 11V
3:0	FS3:0	RW	0100b	Boost converter operation frequency set bits. Default frequency is 400kHz. 0000b = boost converter off 0001b = 100kHz 0010b = 200kHz 0011b = 300kHz 0100b = 400kHz 0101b = 500kHz 0110b = 600kHz 0111b = 700kHz 1000b = 800kHz 1001b = 900kHz

Table 3: LED Current Full-Scale Register

				Addr: 0x02	

Bit	Bit Name	Access	Default	Description
7:0	ILED7:0	RW	00111011b	LED current full scale set bits. The set value corresponds to the 2%-100% external setting current value by a resistor. 0.39% per step. The default value is 25%. 00000000b = 2% 11111111b = 100%

Table 4: Fault Indication Register

				Addr: 0x03
Bit	**Bit Name**	**Access**	**Default**	**Description**
7	DIODEO_F	R	0b	Diode open fault indication bit. 1 = fault 0 = normal
6	OVP_F	R	0b	Output over-voltage fault indication bit. 1 = fault 0 = normal
5	OCP_F	R	0b	Converter over-current fault indication bit. 1 = fault 0 = normal
4	LEDS_F	R	0b	LED string short fault indication bit. 1 = fault 0 = normal
3	LEDO_F	R	0b	LED string open fault indication bit. 1 = fault 0 = normal
2	OTP_F	R	0b	IC over-temperature fault indication bit. 1 = fault 0 = normal
1:0	DIM1:0	R/W	11b	2 LSB bits of LED dimming brightness set bits.

Table 5: Internal LED Dimming Brightness Register

				Addr: 0x04
Bit	**Bit Name**	**Access**	**Default**	**Description**
7:0	DIM9:2	RW	7Fh	8 MSB bits of LED dimming brightness set bits. 0.098% per step. Default value is 50% dimming brightness.

Table 6: OVP and OCP Threshold Register

<table>
<tr><td colspan="5">Addr: 0x05</td></tr>
<tr><td>Bit</td><td>Bit Name</td><td>Access</td><td>Default</td><td>Description</td></tr>
<tr><td>7:3</td><td>OVP4:0</td><td>RW</td><td>11100b</td><td>Output over-voltage protection threshold setting based on the OVP pin connected to the LED anode. 2V/step. Default value is 74V.
00000 = 18V
00001 = 20V
11100 = 74V
11111 = 80V</td></tr>
<tr><td>2:0</td><td>OCP2:0</td><td>RW</td><td>111b</td><td>Converter over-current protection threshold. 50mV/step. Default value is 0.5V.
000 = 0.15V
111 = 0.5V</td></tr>
</table>

Table 7: Vendor ID Register

<table>
<tr><td colspan="5">Addr: 0x06</td></tr>
<tr><td>Bit</td><td>Bit Name</td><td>Access</td><td>Default</td><td>Description</td></tr>
<tr><td>7:0</td><td>ID7:0</td><td>R</td><td>01h</td><td>Vendor ID information.
Returns 01H when read.</td></tr>
</table>

APPLICATION INFORMATION

Selecting the Switching Frequency

The operation frequency of the converter depends on both the resistor at OSC and the FS3:0 bit in register 01H. If a 100kΩ resistor is selected for R_{OSC} (connected to OSC), the switching frequency is set from 100kHz to 900kHz by the I²C interface. 0001b to 1001b corresponds to 100kHz to 900kHz, respectively. Table 8 shows the list of switching frequencies.

Table 8: Switching Frequencies

FS3:0	Switching Frequency	Unit
0000b	Converter off	
0001b	100	
0010b	200	
0011b	300	
0100b	400	
0101b	500	kHz
0110b	600	
0111b	700	
1000b	800	
1001b	900	

Without the I²C interface, an oscillator resistor on OSC sets the internal oscillator frequency for the step-up converter according to Equation (1):

$$F_{SW}(kHz) = \frac{40000}{R_{OSC}(k\Omega)} \qquad (1)$$

When R_{OSC} = 100kΩ, then F_{SW} = 400kHz.

Setting the LED Current

The current of each LED string is set through the current setting resistor on ISET and the full scale LED current setting bits ILED7:0 in Table 3. When the INTERFACE bit in 00H is 0, the LED current is dependent on the input PWM dimming duty cycle. Calculate the setting formula using Equation (2):

$$ILED(mA) = \frac{20196}{R_{ISET}(k\Omega)} * K_{FullScale} \qquad (2)$$

When the INTERFACE bit in 00H is 1, calculate the setting formula using Equation (3):

$$ILED(mA) = \frac{20196}{R_{ISET}(k\Omega)} * K_{DIM} * K_{FullScale} \qquad (3)$$

Where $K_{FullScale}$ is the ratio, which is set by the full scale LED current setting bits ILED7:0 in 02H, and K_{DIM} is the ratio, which is set by the dimming current setting bits DIM9:0 in 03H and 04H.

Without the I²C interface, the current of each LED string is set through the resistor on ISET according to Equation (4):

$$ILED(mA) = \frac{4633}{R_{ISET}(k\Omega)} \qquad (4)$$

For R_{ISET} = 46.4kΩ, the LED current is set to 100mA. Do not leave ISET open.

Selecting the Input Capacitor

The input capacitor reduces the surge current drawn from the input supply and the switching noise from the device. The input capacitor impedance at the switching frequency should be less than the input source impedance to prevent high-frequency switching current from passing through to the input. Ceramic capacitors with X5R or X7R dielectrics are recommended for their low ESR and small temperature coefficients. For most applications, use a 4.7µF ceramic capacitor in parallel with a 220µF electrolytic capacitor.

Selecting the Inductor and Current Sensing Resistor

A larger value inductor results in less ripple current and lower peak inductor current, which reduces stress on the N-channel MOSFET. However, the larger-value inductor has a larger physical size, a higher series resistance, and a lower saturation current. Choose an inductor that will not saturate under the worst-case load conditions. Select the minimum inductor value to ensure that the boost converter works in continuous conduction mode (CCM) with high efficiency and good EMI performance.

Calculate the required inductance value using Equation (5) and Equation (6):

$$L \geq \frac{\eta \times V_{OUT} \times D \times (1-D)^2}{2 \times f_{SW} \times I_{LOAD}} \qquad (5)$$

$$D = 1 - \frac{V_{IN}}{V_{OUT}} \qquad (6)$$

Where V_{IN} is the input voltage, and V_{OUT} is the output voltage, f_{SW} is the switching frequency, I_{LOAD} is the LED load current, and η is the efficiency.

Usually, the switching current is used for peak-current-mode control. To avoid reaching the current limit, the voltage across the sensing resistor (R_{SENSE}) must be less than 70% of the current-limit voltage (V_{SENSE}), in the worst cases. Calculate R_{SENSE} and $I_{L(PEAK)}$ with Equation (7) and Equation (8):

$$R_{SENSE} = \frac{0.7 \times V_{SENSE}}{I_{L(PEAK)}} \qquad (7)$$

$$I_{L(PEAK)} = \frac{V_{OUT} \times I_{LOAD}}{\eta V_{IN}} + \frac{V_{IN} \times (V_{OUT} - V_{IN})}{2 \times L \times F_{SW} \times V_{OUT}} \qquad (8)$$

The current limit setting voltage (V_{SENSE}) is set by the OCP2:0 bits in register 05H.

Selecting the Power MOSFET

The MP3385A is capable of driving a wide variety of N-channel power MOSFETS. The critical parameters of selection for a MOSFET are maximum drain-to-source voltage ($V_{DS(MAX)}$), maximum current ($I_{D(MAX)}$), on resistance ($R_{DS(ON)}$), gate-source charge (Q_{GS}) and gate-drain charge (Q_{GD}), and total gate charge (Q_G).

Ideally, the off-state voltage across the MOSFET is equal to the output voltage. Considering the voltage spike when it turns off, $V_{DS(MAX)}$ should be greater than 1.5 times the output voltage.

The maximum current through the power MOSFET occurs at the minimum input voltage and the maximum output power. The maximum RMS current through the MOSFET is given by Equation (9) and Equation (10):

$$I_{RMS(MAX)} = I_{IN(MAX)} \times \sqrt{D_{MAX}} \qquad (9)$$

$$D_{MAX} \approx \frac{V_{OUT} - V_{IN(MIN)}}{V_{OUT}} \qquad (10)$$

The current rating of the MOSFET should be greater than 1.5 times I_{RMS}.

The on resistance of the MOSFET determines the conduction loss, which can be calculated with Equation (11):

$$P_{cond} = I_{RMS}^{\,2} \times R_{DS(on)} \times k \qquad (11)$$

Where k is the temperature coefficient of the MOSFET.

The switching loss is related to Q_{GD} and Q_{GS}, which determine the commutation time. Q_{GS1} is the charge between the threshold voltage and the plateau voltage when a driver charges the gate, which can be read in the V_{GS} vs. Q_G chart in the MOSFET datasheet. Q_{GD} is the charge during the plateau voltage. These two parameters are needed to estimate turn-on and turn-off losses and can be calculated with Equation (12):

$$P_{SW} = \frac{Q_{GS1} \times R_G}{V_{DR} - V_{TH}} \times V_{DS} \times I_{IN} \times f_{SW} \; + $$
$$\frac{Q_{GD} \times R_G}{V_{DR} - V_{PLT}} \times V_{DS} \times I_{IN} \times f_{SW} \qquad (12)$$

Where V_{TH} is the threshold voltage, V_{PLT} is the plateau voltage, R_G is the gate resistance, and V_{DS} is the drain-source voltage.

Please note that calculating the switching loss is the most difficult part of loss estimation. The formula above provides a simplified equation. For more accurate estimates, the equation becomes much more complex. The total gate charge (Q_G) is used to calculate the gate-drive loss, shown in Equation (13):

$$P_{DR} = Q_G \times V_{DR} \times f_{SW} \qquad (13)$$

Where V_{DR} is the drive voltage.

Selecting the Output Capacitor

The output capacitor keeps the output voltage ripple small and ensures feedback loop stability. The output capacitor impedance must be low at the switching frequency. Ceramic capacitors with X7R dielectrics are recommended for their low ESR characteristics. For most applications, a 4.7µF ceramic capacitor in parallel with a 22µF electrolytic capacitor is sufficient.

Setting the Over-Voltage Protection (OVP)

Open-string protection is achieved through the detection of the voltage on the OVP pin. In some cases, an LED string failure results in the feedback voltage always being zero. The MP3385A continues boosting the output voltage higher and higher. If the output voltage reaches the programmed OVP threshold, the protection is triggered.

To ensure that the chip functions properly, an appropriate OVP voltage is needed. The recommended OVP point is about 1.1 to 1.2 times higher than the output voltage for normal operation. If the OVP pin is connected to the anode of the LED load, the OVP voltage is set by the OVP4:0 bits in register 05H. It is not recommended to set the OVP value higher than 80V, considering the LED return pin voltage rating.

If the MP3385A is applied for >80V output voltage applications through an external extension, connect a proper resistor (R_{OVP}) between the anode of the LED and OVP pins to change the over-voltage point of the output (V_{OVP}). Calculate V_{OVP} with R_{OVP} with Equation (14):

$$V_{OVP}(V) = \frac{R_{OVP}(k\Omega) + 1600}{40} * 1.9 \qquad (14)$$

Where the OVP4:0 bit in register 05H is the set default.

Expanding LED Channels

The MP3385A expands the number of LED channels by using two or three ICs in parallel. To connect two ICs for a total of eight LED strings, tie the VCC pins of the master IC and the slave IC together to power the slave IC internal logic circuitry. Tie the COMP pins of the slave IC and the master IC together to regulate the voltage of all eight strings. The slave IC MOSFET driving signals are not used. The boost converter can be driven only by the master IC. Do not leave IS of the slave IC floating; tie it to ground. Apply the EN and DIM signals to both ICs. The master IC's OVP should be higher than the slave IC's OVP.

PCB Layout Guidelines

Efficient PCB layout is critical to reduce EMI noise and achieve stable operation. For best results, refer to the guidelines below.

1. Keep the loop from the external MOSFET through the output diode and the output capacitor as small and short as possible since they carry a high-frequency pulse current.

2. Separate the power ground (PGND) and signal ground (GND).

3. Connect PGND and GND together. All logic signals refer to the signal ground to reduce noise affection.

4. Place the ceramic capacitors for VIN and VCC as close as possible.
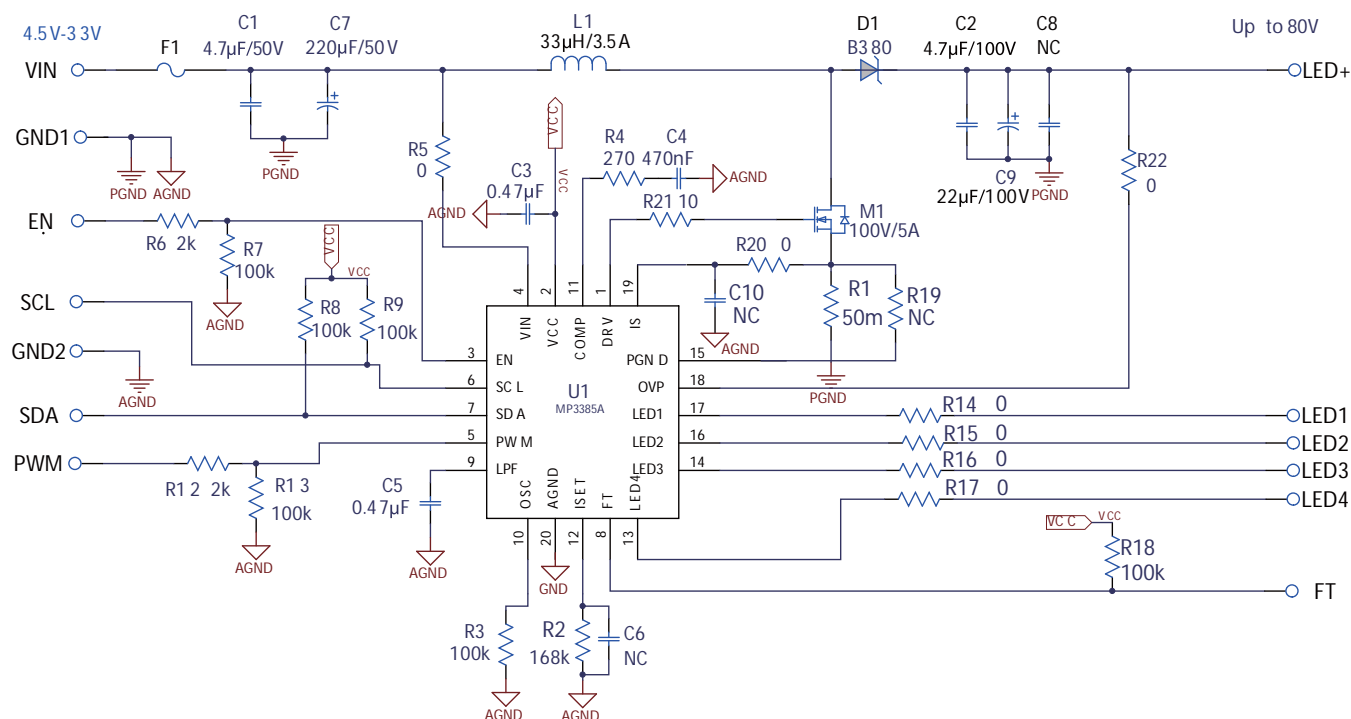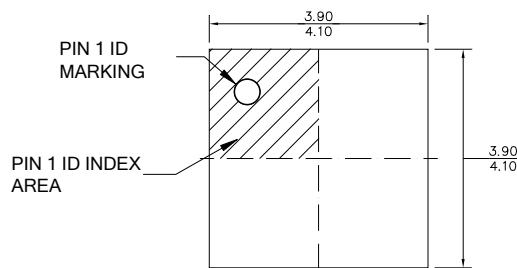
TYPICAL APPLICATION CIRCUIT

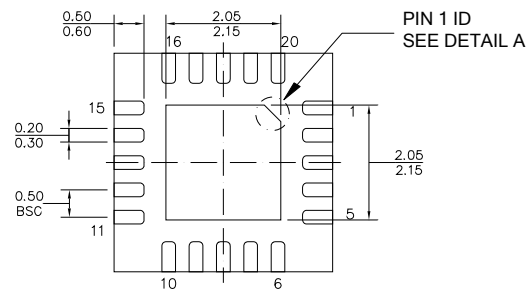
Figure 4: Driving 4 LED Strings

NOTE: Remove the LPF capacitor (C5) when the MP3385A works in direct PWM dimming.
Some components value may need to be adjusted for different application condition.
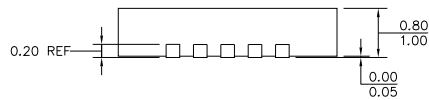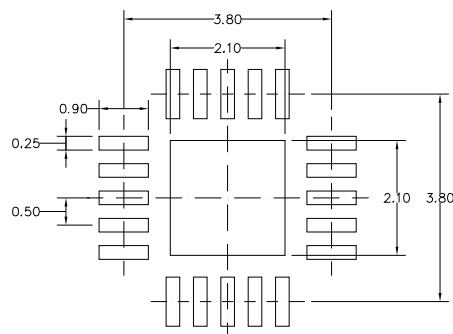
PACKAGE INFORMATION

QFN-20 (4mmx4mm)

PIN 1 ID
MARKING

PIN 1 ID INDEX
AREA

3.90
4.10

3.90
4.10

TOP VIEW

0.50
0.60

2.05
2.15

16   20

PIN 1 ID
SEE DETAIL A

15

0.20
0.30

1

0.50
BSC

2.05
2.15

11

5

10   6

BOTTOM VIEW

0.20 REF

0.80
1.00

0.00
0.05

SIDE VIEW

PIN 1 ID OPTION A
0.30x45° TYP.

PIN 1 ID OPTION B
R0.25 TYP.

DETAIL A

3.80

2.10

0.90

0.25

0.50

2.10   3.80

RECOMMENDED LAND PATTERN

NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) EXPOSED PADDLE SIZE DOES NOT INCLUDE
MOLD FLASH.
3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS
MAX.
4) JEDEC REFERENCE IS MO-220
5) DRAWING IS NOT TO SCALE.

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